

v01.0404

HMC484MS8G

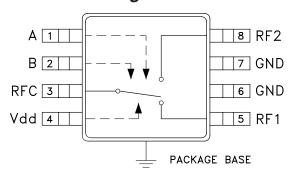
GaAs MMIC 10 WATT T/R SWITCH DC - 3.0 GHz

Typical Applications

The HMC484MS8G is ideal for:

- Wireless Infrastructure
- ISM/Cellular Portables/Handsets
- Automotive Telematics
- Mobile Radio
- Test Equipment

Functional Diagram



Features

High RF Power Handling: > +40 dBm High Third Order Intercept: > +70 dBm Single Positive Supply: +3 to +10 Vdc Low Insertion Loss: 0.4 to 0.6 dB

Ultra Small MSOP8G Package: 14.8 mm²

General Description

The HMC484MS8G is a low-cost SPDT switch in an 8-lead MSOPG package for use in transmit-receive applications which require very low distortion at high input signal power levels, through 10 watts (+40 dBm). The device can control signals from DC to 3.0 GHz. The design provides exceptional intermodulation performance; > +70 dBm third order intercept at +5 volt bias. RF1 and RF2 are reflective shorts when "OFF". On-chip circuitry allows single positive supply operation from +3 Vdc to +10 Vdc at very low DC current with control inputs compatible with CMOS and most TTL logic families.

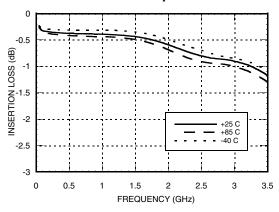
Electrical Specifications,

T_A = +25° C, VctI = 0/+5 Vdc, Vdd = +5 Vdc (Unless Otherwise Stated), 50 Ohm System

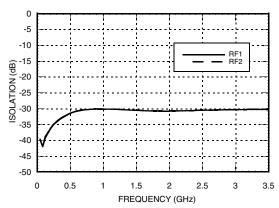
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Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		0.4 0.6 0.8 0.9	0.6 0.8 1.1 1.3	dB dB dB dB
Isolation	DC - 3.0 GHz	26	30		dB
Return Loss (On State)	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		24 20 17 13		dB dB dB dB
	0.5 - 3.0 GHz		32 36 39		dBm dBm dBm
	0.5 - 3.0 GHz	32 37 40	35.5 40 >40		dBm dBm dBm
Input Third Order Intercept (Two-tone input power = +30 dBm each tone)	0.5 - 1.0 GHz 0.5 - 3.0 GHz		72 70		dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	DC - 3.0 GHz		15 40		ns ns



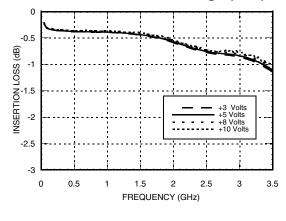
Insertion Loss vs. Temperature



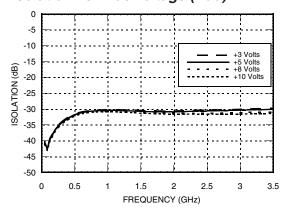
Isolation



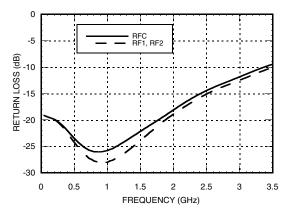
Insertion Loss vs. Bias Voltage (Vdd)



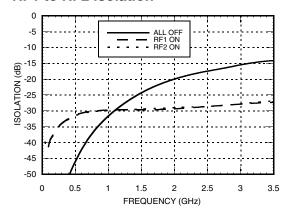
Isolation vs. Bias Voltage (Vdd)



Return Loss

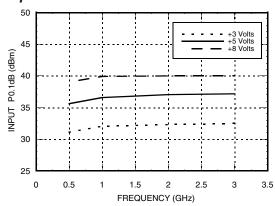


RF1 to RF2 Isolation

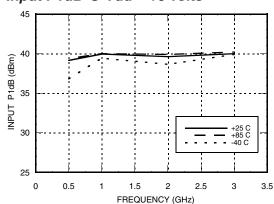




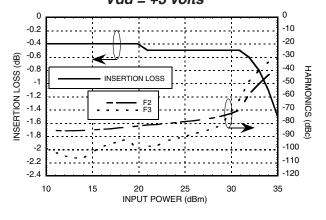
Input P0.1dB vs. Vdd



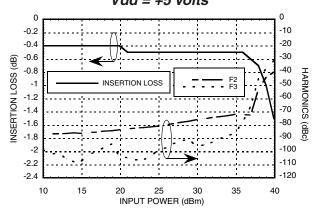
Input P1dB @ Vdd = +5 Volts



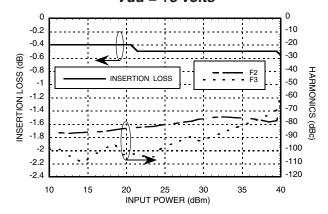
2nd & 3rd Harmonics @ 900 MHz, Vdd = +3 Volts



2nd & 3rd Harmonics @ 900 MHz, Vdd = +5 Volts



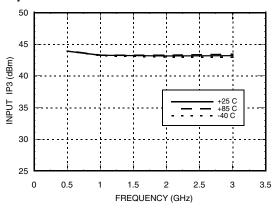
2nd & 3rd Harmonics @ 900 MHz, Vdd = +8 Volts



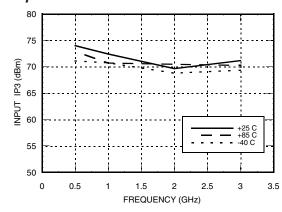
Contact HMC Applications Group for input third order & input compression data from DC - 0.5 GHz.



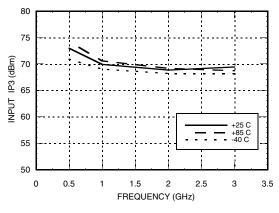
Input IP3 @ Vdd = +3 Volts



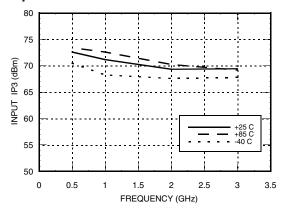
Input IP3 @ Vdd = +5 Volts



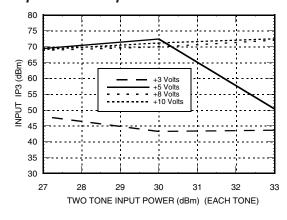
Input IP3 @ Vdd = +8 Volts



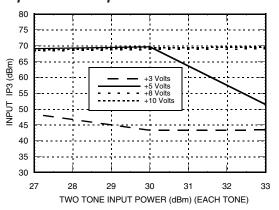
Input IP3 @ Vdd = +10 Volts



Input IP3 vs. Input Power @ 900 MHz



Input IP3 vs. Input Power @ 1900 MHz





Typical 0.5 to 3.0 GHz Compression vs. Bias Voltage (Vdd)

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Bias Vdd	Input Power for 0.1 dB Compression	Input Power for 1.0 dB Compression
(Volts)	(dBm)	(dBm)
+3	32	35.5
+5	36	40
+8	39	>40
+10	>40	>40

Bias Voltage & Current

Vdd (Vdc)	Typical Idd (μA)
+3	0.5
+5	10
+8	50
+10	75

Control Voltages

State	Bias Condition
Low	0 to +0.2 Vdc @ 10 μA Typical
High	Vdd ± 0.2 Vdc @ 10 μA Typical

Absolute Maximum Ratings

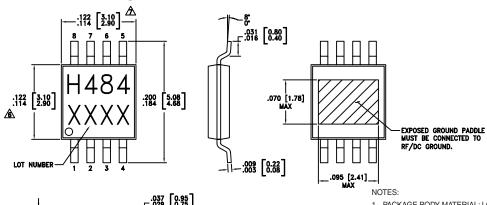
RF Input Power (Vctl = 0V/+8V) (0.5 - 3 GHz)	+40 dBm (T = +85 °C)
Supply Voltage Range (Vdd) (Vctl = 0V)	+13 Vdc
Control Voltage Range (A & B)	Vdd - 13 Vdc to Vdd + 0.7 Vdc
Hot Switch Power Level (Vdd = +8V)	39 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 25 mW/°C above 85 °C)	1.6 W
Thermal Resistance	40 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Note: DC blocking capacitors are required at ports RFC, RF1 and RF2. Their value will determine the lowest transmission frequency.

Truth Table

Control Input (Vctl)		Signal Path State		
Α	В	RFC to RF1	RFC to RF2	
High	Low	Off	On	
Low	High	On	Off	
Low	Low	Off	Off	

Outline Drawing

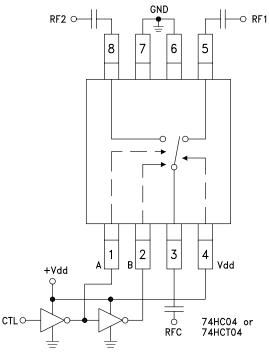


.043 [1.10] .025 [0.75] .025 [0.75] .025 [0.75] .025 [0.75] .025 [0.65] TYP ...

- PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEADFRAME MATERIAL: COPPER ALLOY
- 3. LEADFRAME PLATING: Sn/Pb SOLDER
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- ⚠ DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
- 8. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.



Typical Application Circuit



Notes:

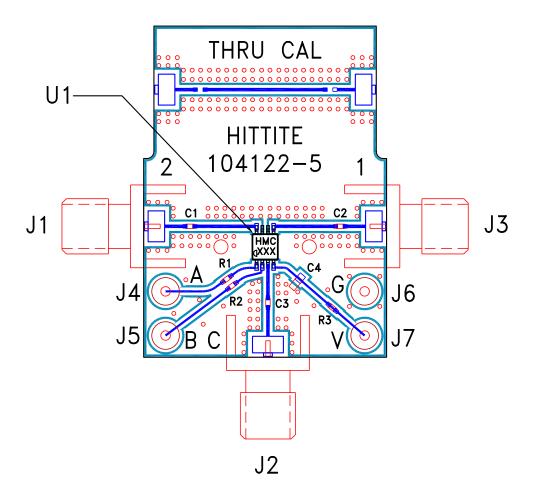
- 1. Set logic gate and switch Vdd = +3V to +10V and use HCT series logic to provide a TTL driver interface.
- 2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of +3 to +10 Volts applied to the CMOS logic gates and to pin 4 of the RF switch.
- DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
- 4. Highest RF signal power capability is achieved with V set to +10V. The switch will operate properly (but at lower RF power capability) at bias voltages down to +3V.

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	А	See truth table and control voltage table.	A,B 0————————————————————————————————————
2	В	See truth table and control voltage table.	
3, 5, 8	RFC, RF1, RF2	This pin is DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
4	Vdd	Supply Voltage	
6, 7	GND	Package bottom must also be connected to PCB RF ground.	



Evaluation Circuit Board



List of Material for Evaluation PCB 104124*

Item	Description
J1 - J3	PC Mount SMA RF Connector
J4 - J7	DC Pin
C1 - C3	100 pF capacitor, 0402 Pkg.
C4	10 KpF capacitor, 0603 Pkg.
R1 - R3	100 Ohm Resistor, 0402 Pkg.
U1	HMC484MS8G T/R Switch
PCB**	104122 PCB
** Circuit Board Material: Rogers 4350	

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

^{*}Reference this number when ordering complete evaluation PCB.





Notes:

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